BCT4228

High-Speed DPDT Analog Switch

FEATURES

♦ V_{CC} Operating Range: 1.65V to 4.5V

♦ Rail-to-Rail Signal Range

♦ ON-Resistance Matching: 0.05 Ω (TYP)

♦ ON-Resistance Flatness: 0.08Ω (TYP)

♦ High Off Isolation: 58dB at 10MHz

♦ 54dB (10MHz) Crosstalk Rejection Reduces Signal Distortion

◆ Break-Before-Make Switching

◆ -3dB Bandwidth: 720MHz

♦ Extended Industrial Temperature Range: –40°C to 85°C

◆ Packaging (Pb-free & Green available)

GENERAL DESCRIPTION

The BCT4228 is a high bandwidth, fast double-pole double-throw (DPDT) analog switch. Its wide bandwidth and low bit-to-bit skew allow it to pass high-speed differential signals with good signal integrity. Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Industry-leading advantages include a propagation delay of less than 250ps, resulting from its low channel resistance and low I/O capacitance. Its high channel-to-channel crosstalk results in minimal noise interference.

APPLICATIONS

Cell Phones

PDAs

Portable Instrumentation

Differential Signal Data Routings

USB 2.0 Signal Routing

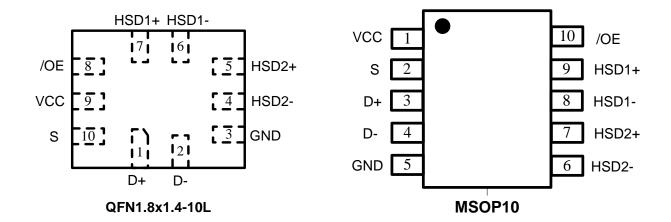
ORDERING INFORMATION

Ordering Code	Package Description	Temp Range	Top Marking	QTY/Reel
BCT4228EGB-TR	QFN1.8x1.4-10L	–40°C to +85°C	ACXX	3000
BCT4228EMB-TR	MSOP10	-40°C to +85°C	4228 XXXXX	4000

Note: "XX" or "XXXXX" in Marking will be appeared as the batch code



PIN CONFIGURATION (Top View)



PIN DESCRIPTION

Pin Number	Name	Description
10	SEL	Select Input
3	GND	Ground
5 , 4	HSD2+, HSD2-	Data Ports 2
7,6	HSD1+,HSD1-	Data Ports 1
1,2	D+, D-	Data Ports
9	VCC	Positive Power Supply
8	/OE	Output Enable

LOGIC FUNCTION TABLE

/OE	SEL	HSD1+,HSD1-	HSD2+,HSD2-
1	X	OFF	OFF
0	0	ON	OFF
0	1	OFF	ON



MAXIMUM RATINGS

Symbol	Pins	Parameter	Value	Unit	
V _{CC}	V _{cc}	Positive DC Supply Voltage	-0.5 to +5.25	V	
	HSD1+,				
	HSD1-,		0.545.V		
V _{IS}	HSD2+,	Analog Signal Voltage	-0.5 to V _{CC} +0.3	V	
	HSD2-				
	D+, D-		-0.5 to +5.25		
V _{IN}	/OE	Control Input Voltage	-0.5 to +5.25	V	
Icc	Vcc	Positive DC Supply Current	50	mA	
Ts		Storage Temperature	-65 to +150	°C	
I _{IN}	/OE	Control Input Current	±20mA	mA	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

ESD PROTECTION

Symbol	Parameter	Value	Unit
ESD	Human Body Model - All Pins	4.0	kV
ESD	Human Body Model - I/O to GND	8.0	kV



RECOMMENDED OPERATING CONDITIONS

Symbol	Pins	Parameter	Min	Max	Unit
Vcc		Positive DC Supply Voltage	1.65	4.5	٧
	HSD1+,				
	HSD1-,		GND	V _{cc}	V
V _{IS}	HSD2+,	Analog Signal Voltage			
	HSD2-				
	D+, D-		GND	4.2	
V _{IN}	/OE	Digital Select Input Voltage	GND	V _{cc}	V
T _A		Operating Temperature Range	-40	+85	°C

Minimum and maximum values are guaranteed through test or design across the Recommended Operating Conditions, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.



DC ELECTRICAL CHARACTERISTICS (Typical: T = 25°C)

BCT4228 SUPPLY AND LEAKAGE CURRENT

	D'	Devemeter	Test Conditions	V _{cc} (V)	-4	0°C to +85°	°C	
Symbol	Pins	Parameter	lest Conditions		Min	Тур	Max	Unit
	\ <u>/</u>	Quiescent	$V_{IS} = V_{CC}$ or GND;	1 65 4 5			1.0	
I _{CC}	Vcc	Supply Current	$I_{OUT} = 0 A$	1.65 -4.5	-	-	1.0	uA
		Increase in I _{CC}						
Ісст	Vcc	per Control	$V_{IN} = 2.6 \ V$	3.6	-	-	10	uA
		Voltage						
	HSD1+,	OFF State						
l _{OZ}	HSD1-, HSD2+,	Leakage	0 ≤ V _{IS} ≤V _{CC}	1.65 - 4.5	-	-	±1.0	uA
	HSD2-	Current						
	D+, D-	Power OFF						
l _{OFF}		Leakage	0 ≤ V _{IS} ≤4.5 V	0	-	-	±1.0	uA
		Current						

BCT4228 DIGITAL INPUT VOLTAGE

Symbol	Pins	Parameter Test Condition	Tost Conditions	V _{cc} (V)	-40°C to +85°C			Unit
	Filis		rest Conditions		Min	Тур	Max	Oilit
	S,/OE	Input High		3.6	1.6	-		V
V _{IH}		Voltage			1.6			
\/	S,/OE	Input Low		3.6		-	0.5	\ <u>'</u>
V _{IL}		Voltage			-			V



BCT4228 HIGH SPEED ON RESISTANCE

Symbol	Dino	Parameter Test Conditions	Toot Conditions	litions V (V)	-40°C to +85°C			- Unit
Symbol	Pins		rest Conditions	V _{CC} (V)	Min	Тур	Max	Unit
			V. = 0.V to 0.4 V	2.7		9.0	12	
R _{ON}	R _{ON}	On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$ $I_{ON} = 8 \text{ mA}$	3.3		8.0	10	Ω
				4.2		7.0	8.0	
	On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$	2.7		1.6			
R _{FLAT}		Flatness		3.3		1.5		Ω
		Flattless	$I_{ON} = 8 \text{ mA}$	4.2		1.4		
		On-Resistance	$V_{IS} = 0 \text{ V to } 0.4 \text{ V},$	2.7		1.6		
R _{ON}				3.3		1.5		Ω
		Matching	I _{ON} =8 mA	4.2		1.4		

BCT4228 DC ELECTRICAL CHARACTERISTICS

(continued) FULL SPEED ON RESISTANCE (Typical: T = 25°C, V_{CC} = 3.3 V)

Comple of	Dina	Donomoton	Test Conditions	V 00	-40°C to +85°C			Unit
Symbol	Pins	Parameter		V _{CC} (V)	Min	Тур	Max	Unit
			V 0.V.tV	2.7		9.0	12	
Ron		On-Resistance	$V_{IS} = 0 \text{ V to } V_{CC},$	3.3		8.5	10.5	Ω
			I _{ON} = 8 mA	4.2		7.5	8.5	
		On-Resistance	$V_{IS} = 0 \text{ V to } V_{CC},$	2.7		1.6		
R _{FLAT}			Flatness $I_{ON} = 8 \text{ mA}$	3.3		1.5		Ω
		riduless		4.2		1.4		
		On-Resistance	$V_{IS} = 0 \text{ V to } V_{CC},$	2.7		2.20		
R _{ON}		Matching	$I_{ON} = 8 \text{ mA}$	3.3		2.45		Ω
		iviatoriirig	ION – O IIIA	4.2		2.65		



BCT4228 AC ELECTRICAL CHARACTERISTICS

TIMING/FREQUENCY (Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50 Ω , C_L = 5 pF, f = 1 MHz)

Cumah al	Dina	Davamatar	eter Test Conditions	V 00	-40)°C to +85°	°C	- Unit
Symbol	Pins	Parameter	rest Conditions	V _{CC} (V)	Min	Тур	Max	
t _{ON}	Closed to	Turn ON Time	Soo toot circuit 2	1.65 - 4.5		14	30	20
	Open	Turn-ON Time	See test circuit 2	1.05 - 4.5		14	30	ns
t _{OFF}	Open to	Turn-OFF Time	See test circuit 2	1.65 - 4.5		10	20	ns
OFF	Closed	Tum-OFF Time	See lest circuit 2	1.03 - 4.3		10	20	10
t		Break-Before-Make	See test circuit 1	1.65 - 4.5	3.0	4.4	7.0	ns
t _{BBM}		Delay	See lest circuit 1	1.03 - 4.3	5.0	4.4	7.0	110
BW/		-3 dB Bandwidth	C _L = 5 pF	1.65 - 4.5		650		MHz
BW		-3 dB Bandwidth	C _L = 0 pF	1.00 - 4.5		720		IVI□∠

BCT4228 ISOLATION

(Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50 Ω , C_L = 5 pF)

Symbol	Pins	ns Parameter	Test Conditions	V _{cc} (V)	-40°C to +85°C			Unit
	Pins				Min	Тур	Max	Oilit
OIDD O	0	Open OFF-Isolation	f = 10 MHz	1.65 -		50		-ID
OIRR	Open			4.5		-58		dB
\/ T A11/	HSD1+	Non-Adjacent		1.65 -		5.4		j
XTALK to F	to HSD1-	Channel Crosstalk	f = 10 MHz	4.5		-54		dB

BCT4228 CAPACITANCE

(Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50 Ω , C_L = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	-40°C to +85°C			11
				Min	Тур	Max	Unit
C _{IN}	OE	Control Pin Input	V _{CC} = 0 V	-	3.0	-	pF
		Capacitance					
C _{ON}	D+ to	ON Capacitance	V _{CC} = 3.3 V; OE = 0 V	-	8.0	-	pF
	HSD1+ or						
	HSD2+						
C _{OFF}	HSD2+,	OFF Capacitance	V _{CC} = V _{IS} = 3.3 V; OE	-	4.5	-	pF
	HSD2-		= 3.3 V				

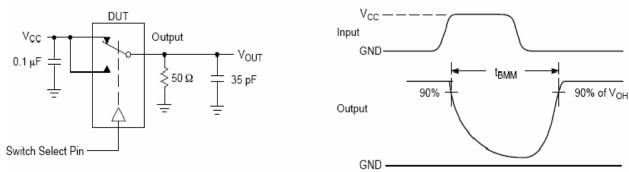


Figure 1. t_{BBM} (Time Break-Before-Make)

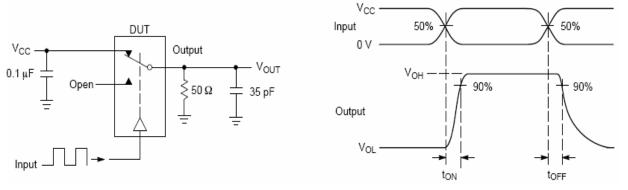


Figure 2. t_{ON} / t_{OFF}



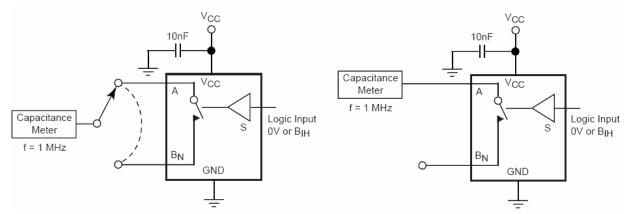


Figure 3. Channel ON/OFF Capacitance

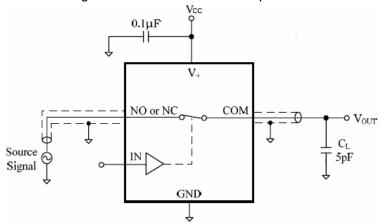


Figure 4. Bandwidth -3dB

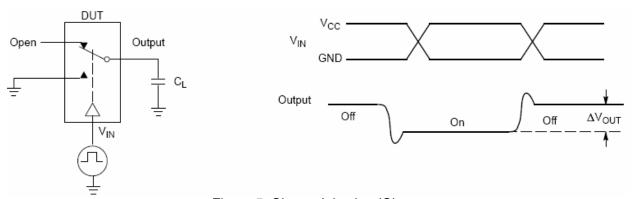


Figure 5. Charge Injecting (Q)



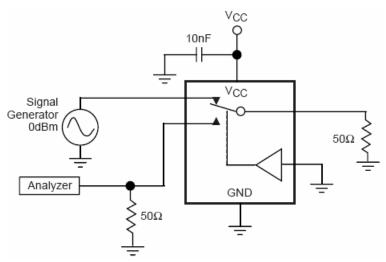
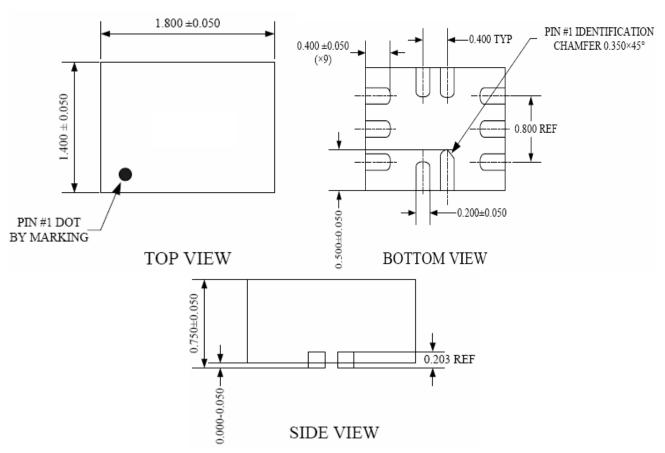


Figure 6. Crosstalk



Package Information

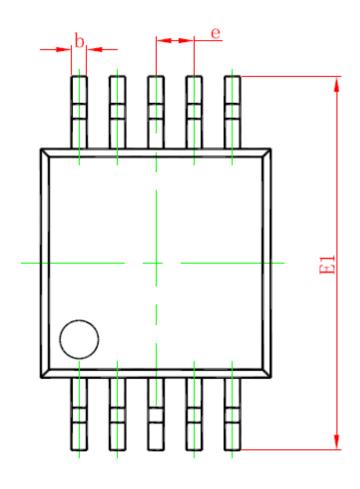
QFN1.8x1.4-10L

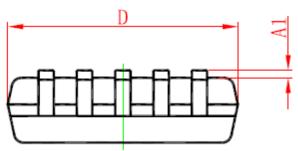


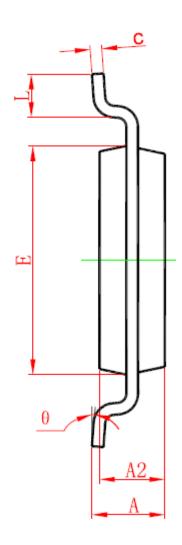
Note: All linear dimensions are in millimeters.



Package Information MSOP10









01	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0. 820	1. 100	0. 032	0. 043	
A1	0. 020	0. 150	0. 001	0.006	
A2	0. 750	0. 950	0.030	0. 037	
b	0. 180	0. 280	0.007	0. 011	
С	0.090	0. 230	0.004	0.009	
D	2. 900	3. 100	0. 114	0. 122	
e	0.50(BSC)		0.020(BSC)		
E	2. 900	3. 100	0. 114	0. 122	
E 1	4. 750	5. 050	0. 187	0. 199	
L	0. 400	0.800	0. 016	0. 031	
θ	0°	6°	0°	6°	

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Analogue Switch ICs category:

Click to view products by BROADCHIP manufacturer:

Other Similar products are found below:

FSA3051TMX NLAS4684FCTCG NLAS5223BLMNR2G NLVAS4599DTT1G NLX2G66DMUTCG 425541DB 425528R 099044FB

MAX4762ETB+ NLAS5123MNR2G PI5A4157CEX PI5A4599BCEX NLAS4717EPFCT1G PI5A3167CCEX SLAS3158MNR2G

PI5A392AQEX PI5A392AQE FSA634UCX ADG714BCPZ-REEL7 HT4051ARZ TC4066BP(N,F) DG302BDJ-E3 ADG854BCPZ-REEL7

PI5A100WE PI5A100QEX HV2733FG-G HV2701FG-G HV2301FG-G HV2301FG-G-M931 RS2117YUTQK10 RS2118YUTQK10

RS2227XUTQK10 ADG452BRZ-REEL7 MAX391CPE+ MAX4744ELB+ MAX4730EXT+T MAX4730ELT+ MAX333AEWP+

BU4066BC MAX313CPE+ BU4S66G2-TR NLASB3157MTR2G NX3L4684TK,115 NX5L2750CGUX NLAS4157DFT2G

NLAS4599DFT2G NLASB3157DFT2G NLAST4599DFT2G NLAST4599DTT1G DG300BDJ-E3